Docket No. 5000-5118

## UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s)

Tomohei SUGIYAMA et al.

Group Art Unit:

2891

Serial No

10/626,418

Examiner:

D. Menz

Filed

July 23, 2003

For

METHOD OF MANUFACTURING A LOW EXPANSION MATERIAL

AND SEMICONDUCTOR DEVICE USING THE LOW EXPANSION

**MATERIAL** 

## RESPONSE TO REQUIREMENT FOR RESTRICTION

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In the May 4, 2005 Office Action, the Examiner issued a restriction requirement, requiring Applicants to elect one of four groups of claims:

- "Claim 1-8, drawn to a method of manufacturing a low expansion material, I. classified in class 75, subclass 330";
- "Claims 9-10, drawn to a semiconductor device, classified in class 257, subclass II. 741";
- "Claims 11-12, drawn to a semiconductor device with a semiconductor element III. mounted directly to a heat sink, classified in class 257, subclass 707"; or
- "Claims 13-14, drawn to a semiconductor device with a heat releasing plate, AFERE PRIMITE ENERGY classified in class 257, subclass 712."

Applicants provisionally elect Group III, claims 11-12.

Applicants furthermore respectfully traverse the Examiner's restriction requirement.

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